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Pellicle filter structure for photo mask PDerwent Titie:

HYNIX SEMICONDUCTOR INC Non-standard company

曾Inventor: WON J I;

2004-363005 / 200434 

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**@**Manual Codes: U11-C04D(Masking techniques for microlithography), U11-

C04E1(Apparatus and method for photolithography)

**⊕** Derwent Abstract:

(KR4001785A) Novelty - A pellicle filter structure for a photo mask is provided to be capable of preventing the contamination due to chemicals by installing a chemical

filter at the outer surface of an air filter.

Detailed Description - A pellicle filter structure for a photo mask is provided with a pellicle(10) made of transparent film capable of transmitting light, a frame(20) for supporting the lower portion of the pellicle, a vent hole(30) formed at the inner portion of the frame for flowing air, and an air filter(40) installed at the outer surface of the frame for blocking the vent hole in order to filter foreign substance. The pellicle filter structure further includes a chemical filter(50) installed at the outer surface of the air filter for preventing chemicals from being flowed into the vent hole.

**♥Images:**



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XINYH

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(72)Inventor:

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SEMICONDUCTOR INC. WON, JUN IL

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(54) PELLICLE FILTER STRUCTURE FOR PHOTO MASK

(57) Abstract:

PURPOSE: A pellicle filter structure for a photo mask is provided to be capable of preventing the contamination due to chemicals by installing a chemical filter at the outer surface of an air filter.

CONSTITUTION: A pellicle filter structure for a photo mask is provided with a pellicle(10) made of transparent film capable of transmitting light, a frame(20) for supporting the lower portion of the pellicle, a vent hole(30) formed at the inner portion of the frame for flowing air, and an air filter(40)

installed at the outer surface of the frame for blocking the vent hole in order to filter foreign substance. The pellicle filter structure further includes a chemical filter(50) installed at the outer surface of the air filter for preventing chemicals from being flowed into the vent hole.

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